

# 2SA1262

Silicon PNP Epitaxial Planar Transistor (Complement to type 2SC3179)

Application : Audio and General Purpose

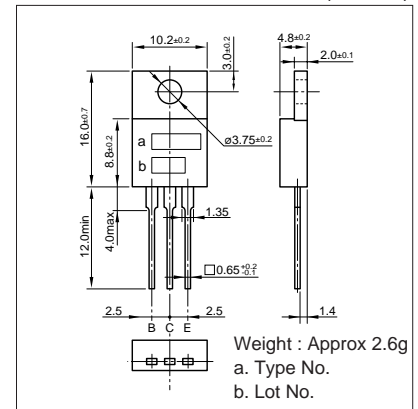
**Absolute maximum ratings** (Ta=25°C)

Symbol	2SA1262	Unit
V <sub>CB0</sub>	-60	V
V <sub>CE0</sub>	-60	V
V <sub>EB0</sub>	-6	V
I <sub>c</sub>	-4	A
I <sub>B</sub>	-1	A
P <sub>c</sub>	30(T <sub>c</sub> =25°C)	W
T <sub>j</sub>	150	°C
T <sub>stg</sub>	-55 to +150	°C

**Electrical Characteristics** (Ta=25°C)

Symbol	Conditions	2SA1262	Unit
I <sub>CB0</sub>	V <sub>CB</sub> =-60V	-100max	μA
I <sub>EB0</sub>	V <sub>EB</sub> =-6V	-100max	μA
V(BR) <sub>CEO</sub>	I <sub>c</sub> =-25mA	-60min	V
h <sub>FE</sub>	V <sub>CE</sub> =-4V, I <sub>c</sub> =-1A	40min	
V <sub>CE(sat)</sub>	I <sub>c</sub> =-2A, I <sub>B</sub> =-0.2A	-0.6max	V
f <sub>r</sub>	V <sub>CE</sub> =-12V, I <sub>E</sub> =0.2A	15typ	MHZ
C <sub>oB</sub>	V <sub>CB</sub> =-10V, f=1MHz	90typ	pF

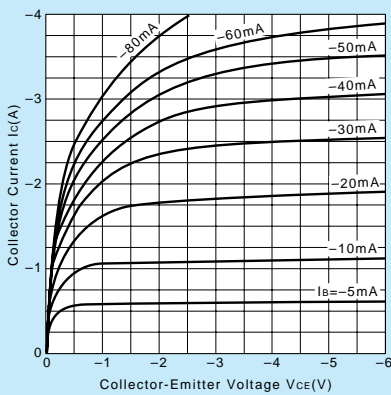
**External Dimensions MT-25(TO220)**



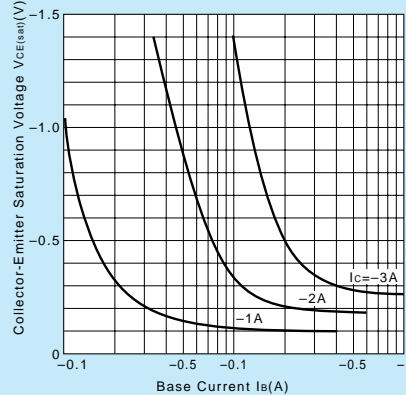
**Typical Switching Characteristics (Common Emitter)**

V <sub>CC</sub> (V)	R <sub>L</sub> (Ω)	I <sub>c</sub> (A)	V <sub>BB1</sub> (V)	V <sub>BB2</sub> (V)	I <sub>B1</sub> (mA)	I <sub>B2</sub> (mA)	t <sub>on</sub> (μs)	t <sub>stg</sub> (μs)	t <sub>f</sub> (μs)
-20	10	-2	-10	5	-200	200	0.25typ	0.75typ	0.25typ

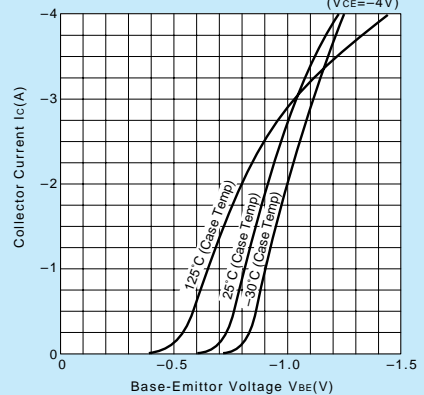
**I<sub>c</sub>-V<sub>CE</sub> Characteristics (Typical)**



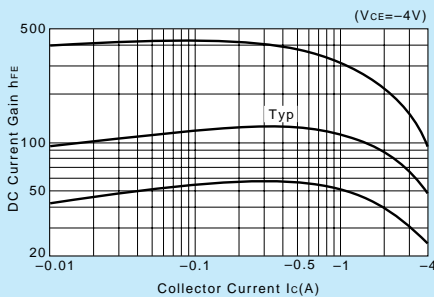
**V<sub>CE(sat)</sub>-I<sub>B</sub> Characteristics (Typical)**



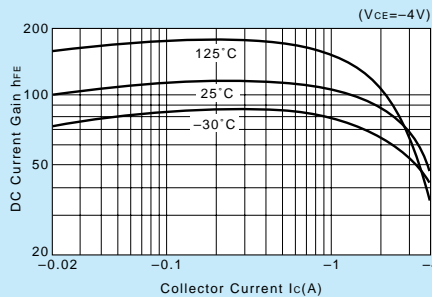
**I<sub>c</sub>-V<sub>BE</sub> Temperature Characteristics (Typical)**



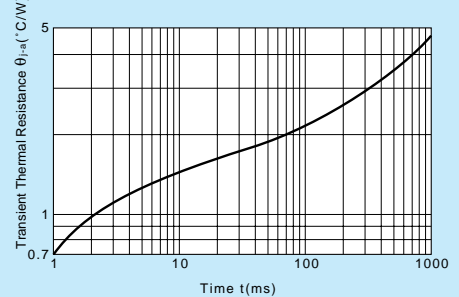
**h<sub>FE</sub>-I<sub>c</sub> Characteristics (Typical)**



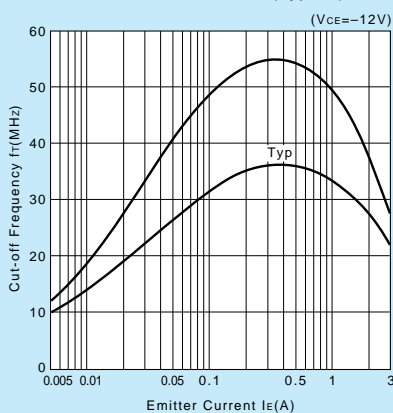
**h<sub>FE</sub>-I<sub>c</sub> Temperature Characteristics (Typical)**



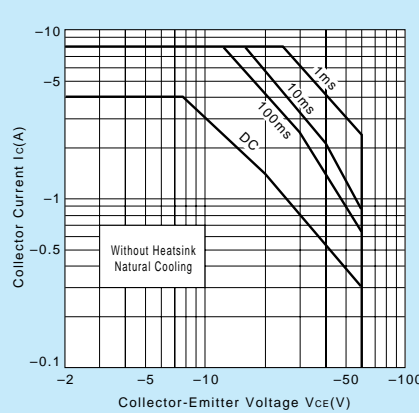
**θ<sub>j-a</sub>-t Characteristics**



**f<sub>T</sub>-I<sub>E</sub> Characteristics (Typical)**



**Safe Operating Area (Single Pulse)**



**P<sub>c</sub>-T<sub>a</sub> Derating**

